

# VRFS0003 - BD

## DC-20GHz GaAs pHEMT SP4T Switch



www.viper-rf.com

### ADVANCE INFORMATION

Version 0.2



### KEY FEATURES:

- DC – 20 GHz reflective SP4T
- Insertion Loss — 2.7 dB
- High Isolation — 38 dB
- Size: 1.5 x 3 x 0.1 mm
- Available as a bare die

### DESCRIPTION:

The VRFS0003-BD is a DC – 20 GHz reflective single-pole four-throw switch for Defence and Instrumentation markets. It is manufactured on 0.5  $\mu\text{m}$  GaAs pHEMT process. The circuit demonstrates over 38 dB isolation across the band (52 dB at 10 GHz), with a insertion loss of 2.7 dB at 20 GHz. It is available as a bare die.

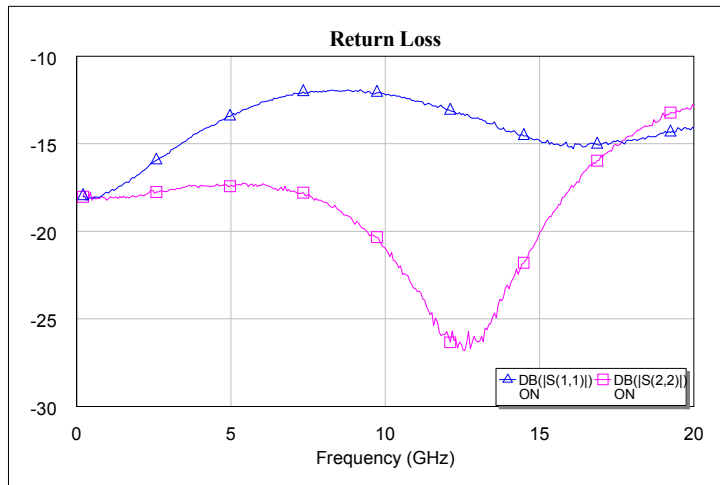
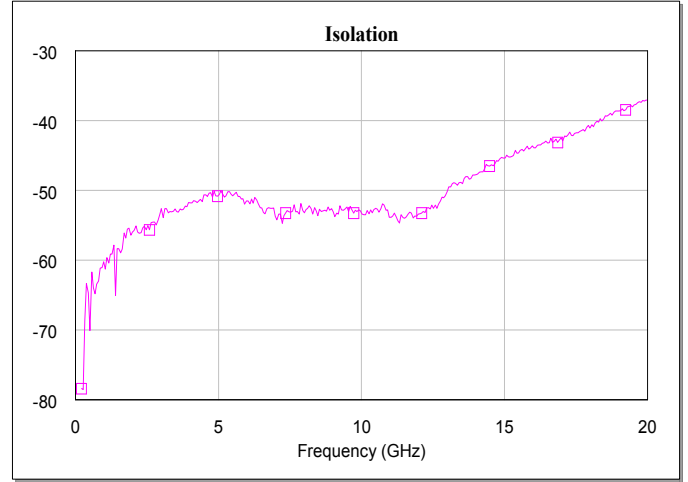
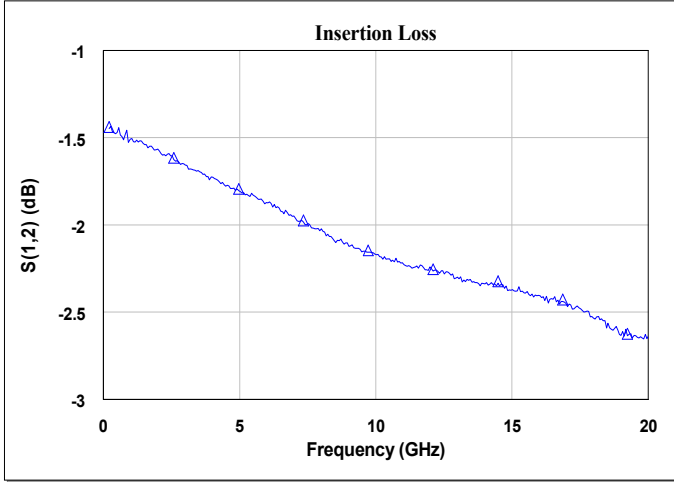
### ELECTRICAL SPECIFICATIONS:

Parameter	Specification			Unit	Condition
	Typ @ 1GHz	Typ @ 10GHz	Typ @ 20GHz		
Insertion Loss	-1.5	-2.2	-2.7	dB	$f_0 = \text{DC} - 20\text{GHz}$
Isolation	-62	-52	-38	dB	$f_0 = \text{DC} - 20\text{GHz}$
I/P Return Loss	-18	-12	-14	dB	$f_0 = \text{DC} - 20\text{GHz}$ Any arm, ON state
O/P Return Loss	-18	-21	-13	dB	$f_0 = \text{DC} - 20\text{GHz}$ RF1, RF2, ON state
Input power for 1dB compression		23		dBm	$f_0 = 0.5 - 20\text{GHz}$

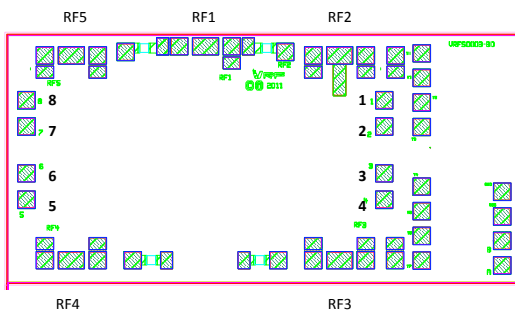
Notes: Specifications are at 25°C,  $V_{\text{ctrl}} = 0\text{V} / -5\text{V}$ ,  $Z = 50\ \Omega$ , For all RF specifications, reference plane is at the bondpad

## MEASURED PERFORMANCE: (On-Wafer Measurements)

TA = 25°C, V<sub>CTRL</sub> = -5V (low) and 0V (high)



## Die Padout and Truth Table:



Low Loss State	V1(V)	V2(V)	V3(V)	V4(V)	V5(V)	V6(V)	V7(V)	V8(V)
RF1-RF2	0	-5	0	-5	-5	0	0	-5
RF1-RF3	-5	0	-5	0	-5	0	0	-5
RF1-RF4	-5	0	0	-5	0	-5	0	-5
RF1-RF5	-5	0	0	-5	-5	0	-5	0